

#### Electrical Specifications (Ta = 25°C unless otherwise noted)

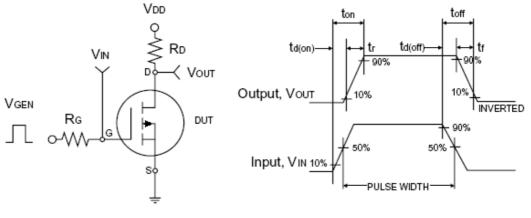
Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static					1	
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250 \mu A$	BV <sub>DSS</sub>	20			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	V <sub>GS(TH)</sub>	0.6	0.8	1.2	V
Gate Body Leakage	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 16V, V_{GS} = 0V$	I <sub>DSS</sub>			1.0	μA
On-State Drain Current	$V_{DS} \ge 10V, V_{GS} = 4.5V$	I <sub>D(ON)</sub>	15			Α
	$V_{GS} = 4.5V, I_{D} = 4A$			24	30	
Drain-Source On-State Resistance	$V_{GS} = 2.5V, I_D = 3.2A$ $R_{DS(ON)}$			32	40	mΩ
	$V_{GS} = 1.8V, I_{D} = 2A$			80	100	
Forward Transconductance	$V_{DS} = 15V, I_{D} = 4A$	g <sub>fs</sub>		40		S
Diode Forward Voltage	I <sub>S</sub> = 1.6A, V <sub>GS</sub> = 0V	V <sub>SD</sub>		0.8	1.2	V
Dynamic <sup>b</sup>	•				•	
Total Gate Charge		Qg		8.6		
Gate-Source Charge	$V_{DS} = 10V, I_D = 4A,$	Q <sub>gs</sub>		2		nC
Gate-Drain Charge	V <sub>GS</sub> = 4.5V	$Q_{gd}$		2.7		
Input Capacitance		C <sub>iss</sub>		550		
Output Capacitance	$V_{DS} = 10V, V_{GS} = 0V,$	C <sub>oss</sub>		100		pF
Reverse Transfer Capacitance	f = 1.0MHz	C <sub>rss</sub>		30		
Switching <sup>c</sup>						
Turn-On Delay Time		t <sub>d(on)</sub>		15		
Turn-On Rise Time	$V_{DD} = 10V, R_L = 10\Omega,$	t <sub>r</sub>		20		
Turn-Off Delay Time	$I_{\rm D} = 1$ A, $V_{\rm GEN} = 4.5$ V,	t <sub>d(off)</sub>		40		nS
Turn-Off Fall Time	$R_{G} = 6\Omega$	t <sub>f</sub>		8		]

Notes:

a. pulse test: PW  $\leq$ 300µS, duty cycle  $\leq$ 2%

b. For DESIGN AID ONLY, not subject to production testing.

b. Switching time is essentially independent of operating temperature.

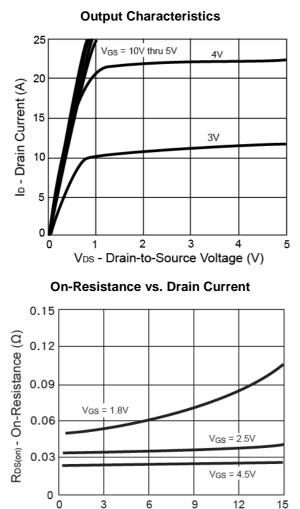


Switching Test Circuit

Switchin Waveforms

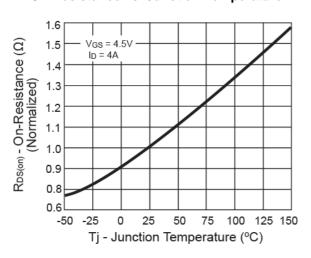


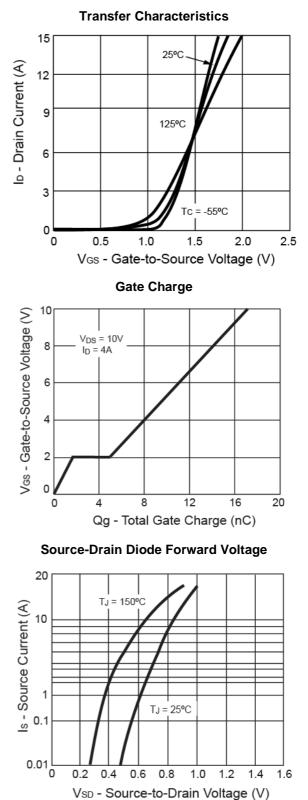
#### Electrical Characteristics Curve (Ta = 25<sup>\o</sup>C, unless otherwise noted)



**On-Resistance vs. Junction Temperature** 

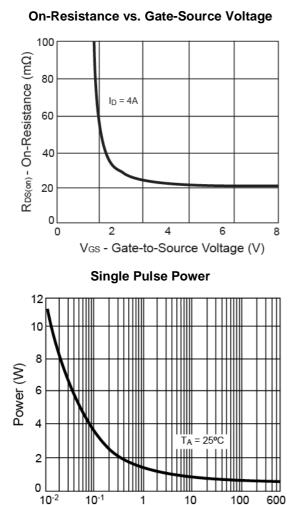
ID - Drain Current (A)



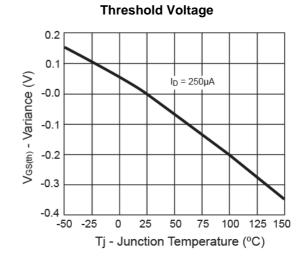




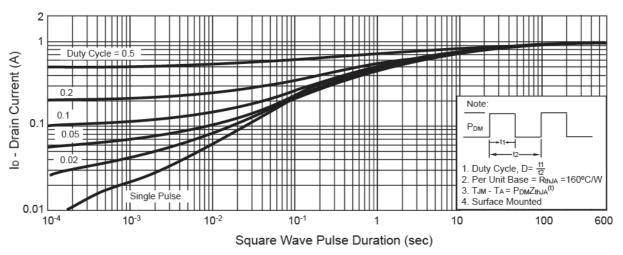
#### Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)



Tiime (sec)



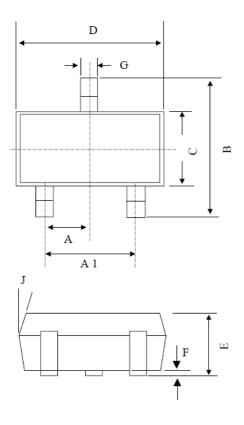
Normalized Thermal Transient Impedance, Junction-to-Ambient

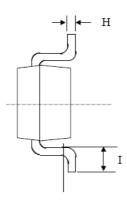


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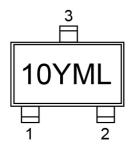
### SOT-23 Mechanical Drawing





1									
	SOT-23 DIMENSION								
	DIM	MILLIM	ETERS	INCHES					
		MIN	MAX	MIN	MAX.				
	А	0.95	BSC	0.037 BSC					
	A1	1.9	BSC	0.074 BSC					
I	В	2.60	3.00	0.102	0.118				
	С	1.40	1.70	0.055	0.067				
	D	2.80	3.10	0.110	0.122				
	Е	1.00	1.30	0.039	0.051				
	F	0.00	0.10	0.000	0.004				
	G	0.35	0.50	0.014	0.020				
	Н	0.10	0.20	0.004	0.008				
	Ι	0.30	0.60	0.012	0.024				
	J	5°	10º	5°	10º				

### Marking Diagram



<b>10</b> = Device Code	e					
Y = Year Code						
M = Month Code for Halogen Free Product						
<b>O</b> =Jan	P =Feb	<b>Q</b> =Mar	R =Apr			
<b>S</b> =May	<b>T</b> =Jun	U =Jul	V =Aug			
W =Sep	X =Oct	Y =Nov	<b>Z</b> =Dec			
L = Lot Code						



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